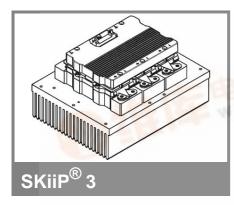
#### 捷多邦,专业PCB打样工厂,24小时加急出货

## SKiiP 1513GB172-3DL



## 2-pack-integrated intelligent Power System

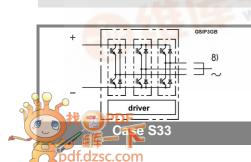
Power section

SKiiP 1513GB172-3DL

Preliminary Data

## Features

- SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated teperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP<sup>®</sup> 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- AC connection busbars must be connected by the user; copper busbars available on request



Absolute Maximum Ratings T <sub>s</sub> = 25 °C, unless otherwise specifie							
Symbol Conditions		Values	Units				
IGBT	12 10 1						
V <sub>CES</sub>	Mag	1700	V				
V <sub>CES</sub> V <sub>CC</sub> <sup>1)</sup>	Operating DC link voltage	1200	V				
V <sub>GES</sub>		± 20	V				
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1500 (1125)	Α				
Inverse diode							
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1250 (950)	A				
I <sub>FSM</sub>	T <sub>j</sub> = 150 °C, t <sub>p</sub> = 10 ms; sin	10200	A				
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	520	kA²s				
T <sub>j</sub> , (T <sub>stg</sub> )		- 40 + 150 (125)	°C				
V <sub>isol</sub>	rms, AC, 1 min, m <mark>ain termin</mark> als to heat sink	4000	V				
I <sub>AC-terminal</sub>	per AC terminal, rms, T <sub>s</sub> = 70 °C,	400	А				
77	T <sub>terminal</sub> < 115 °C						

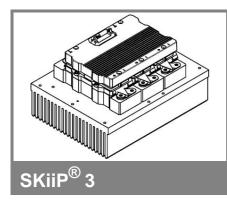
Characteristics		$T_s$ = 25 °C, unless otherwise specifi			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
V <sub>CEsat</sub>	$I_{C} = 900 \text{ A}, T_{j} = 25 (125) \text{ °C};$ measured at terminal	= E	1,9 (2,2)	2,4	V
V <sub>CEO</sub>	T <sub>i</sub> = 25 (125) °C; at terminal	ALC: W	1 (0,9)	1,2 (1,1)	V
r <sub>CE</sub>	T <sub>i</sub> = 25 (125) °C; at terminal	1000	1 (1,4)	1,3 (1,7)	mΩ
I <sub>CES</sub>	V <sub>GE</sub> = 0 V, V <sub>CE</sub> = V <sub>CES</sub> , T <sub>i</sub> = 25 (125) °C		3,6 (216)		mA
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 900 A, V <sub>CC</sub> = 900 V		585		mJ
LIVI.DZ	T <sub>j</sub> = 125 °C, V <sub>CC</sub> = 1200 V		863		mJ
R <sub>CC+EE</sub> '	terminal chip, T <sub>i</sub> = 25 °C		0,17		mΩ
L <sub>CE</sub>	top, bottom		4		nH
C <sub>CHC</sub>	per phase, AC-side		5,1		nF
Inverse o	Inverse diode				
V <sub>F</sub> = V <sub>EC</sub>	$I_F = 900 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ measured at terminal	E B	2 (1,8)	2,15	V
V <sub>TO</sub>	T <sub>i</sub> = 25 (125) °C		1,1 (0,8)	1,2 (0,9)	V
r <sub>T</sub>	T <sub>i</sub> = 25 (125) °C		1 (1,1)	1,1 (1,2)	mΩ
Err	$I_{\rm C} = 900  {\rm A},  {\rm V}_{\rm CC} = 900  {\rm V}$		108		mJ
5 24	T <sub>j</sub> = 125 °C, V <sub>CC</sub> = 1200 V		128		mJ
Mechani	cal data	•			
M <sub>dc</sub>	DC terminals, SI Units	6		8	Nm
M <sub>ac</sub>	AC terminals, SI Units	13		15	Nm
w	SKiiP <sup>®</sup> 3 System w/o heat sink		2,4		kg
w	heat sink	1.1	7,5	2200	kg

#### Thermal characteristics (PX 16 heat sink with fan SKF16B-230-1); "s" reference to heat sink; "r" reference to built-in temperature sensor (acc.IEC 60747-15)

R <sub>th(j-s)I</sub>	per IGB	т					0,02	K/W	
R <sub>th(j-s)D</sub>	per dioc	le					0,038	K/W	
Z <sub>th</sub>	R <sub>i</sub> (mK/W) (max. values)				tau <sub>i</sub> (s)				
WW.DE	1	2	3	4	1	2	3	4	
Z <sub>th(j-r)I</sub>	3,4	9,6	7	0	363	0,18	0,04	1	
Z <sub>th(j-r)D</sub>	12	12	18	20	30	5	0,25	0,04	
Z <sub>th(r-a)</sub>	2,1	20	5,5	1,4	210	85	11	0,4	

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# SKiiP 1513GB172-3DL



## 2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 1513GB172-3DL

Preliminary Data

### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only )
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute Maximum Ratings		Т <sub>а</sub>	$T_a = 25 \text{ °C}$ , unless otherwise specified			
Symbol	Conditions		Values	Units		
V <sub>S2</sub>	unstabilized 24 V power supply		30	V		
V <sub>i</sub>	input signal voltage (high)		15 + 0,3	V		
dv/dt	secondary to primary side		75	kV/µs		
V <sub>isollO</sub>	input / output (AC, rms, 2 s)		4000	V		
VisoIPD	partial discharge extinction voltage, rms, $Q_{PD} \le 10 \text{ pC}$ ;		1500	V		
V <sub>isol12</sub>	output 1 / output 2 (AC, rms, 2 s)		1500	V		
f <sub>sw</sub>	switching frequency		9	kHz		
f <sub>out</sub>	output frequency for I=I <sub>C</sub> ; sin.		1	kHz		
T <sub>op</sub> (T <sub>stg</sub> )	operating / storage temperature		- 40 + 85	°C		

Characte	eristics	(T <sub>a</sub> =			= 25 °C)
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S2</sub>	supply voltage non stabilized	13	24	30	V
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	380+34*f/kHz+0,00015*(I <sub>AC</sub> /A) <sup>2</sup>			mA
V <sub>iT+</sub>	input threshold voltage (High)			12,3	V
V <sub>iT-</sub>	input threshold voltage (Low)	4,6			V
R <sub>IN</sub>	input resistance		10		kΩ
CIN	input capacitance		1		nF
t <sub>d(on)IO</sub>	input-output turn-on propagation time input-output turn-off propagation time		1,3 1,3		μs µs
t <sub>d(off)IO</sub> t <sub>pERRRESET</sub>	error memory reset time		9		μs
t <sub>TD</sub>	top / bottom switch interlock time		3,3		μs
l <sub>analogOUT</sub>	max. 5 mA; 8 V corresponds to 15 V supply voltage for external components		1500		A
I <sub>s1out</sub>	max. load current			50	mA
I <sub>TRIPSC</sub>	over current trip level (I <sub>analog</sub> OUT = 10 V)	110	1875	400	A
T <sub>tp</sub> U <sub>DCTRIP</sub>	over temperature protection U <sub>DC</sub> -protection ( U <sub>analog OUT</sub> = 9 V);	110	not implemented	120 d	°C V
	(option for GB types)				

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